## G eneralized E lliott-Y afet theory of electron spin relaxation in m etals: the origin of the anom alous electron spin life-time in M gB<sub>2</sub>

F. Simon,<sup>1</sup>, B. Dora,<sup>1,2</sup> F. Murany<sup>4</sup>,<sup>1</sup> A. Janossy,<sup>1</sup> S. Gara<sup>3</sup>, L. Forro,<sup>3</sup> S. Bud'ko,<sup>4</sup> C. Petrovic<sup>z</sup>,<sup>4</sup> and P. C. Can eld<sup>4</sup>

<sup>1</sup>Budapest University of Technology and Economics,

Institute of Physics and Condensed M atter Research G roup of the Hungarian Academ y of Sciences, H-1521 Budapest, Hungary <sup>2</sup>M ax-P lanck-Institut fur Physik K om plexer System e, Nothnitzer Str. 38, 01187 D resden, G erm any

<sup>3</sup>Institute of Physics of Complex M atter, FBS Swiss Federal Institute of Technology (EPFL), CH-1015 Lausanne, Switzerland

<sup>4</sup>Am es Laboratory, U.S. Department of Energy and Department of

Physics and Astronomy, Iowa State University, Ames, Iowa 50011, USA

The tem perature dependence of the electron spin relaxation time in M gB<sub>2</sub> is anom alous as it does not follow the tem perature dependence of the resistivity above 150 K, it has a maximum around 400 K, and it decreases for higher tem peratures. This violates the well established E lliot-Y afet theory of electron spin relaxation in metals. We show that the anomaly occurs when the quasiparticle scattering rate (in energy units) becomes comparable to the energy di erence between the conduction- and a neighboring band. We indicate the anomalous behavior is related to the unique band structure of M gB<sub>2</sub> and the large electron-phonon coupling. The saturating spin-lattice relaxation can be regarded as the spin transport analogue of the Io e-R egel criterion of electron transport.

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K now ledge of the electron spin-lattice relaxation time, T<sub>1</sub>, of conduction electrons plays a central role in assessing the applicability of metals for information processing using electron spins, spintronics [1].  $T_1$  is the time it takes for the conduction electron spin ensemble to relax to its therm al equilibrium magnetization after a non-equilibrium magnetization has been induced e.g. by conduction electron-spin resonance (CESR) excitation [2] orby a spin-polarized current [1]. The Elliott-Yafet (EY) theory of  $T_1$  in m etals [3, 4] has been well established in the past 50 years on various systems such as elemental m etals [5], strongly correlated one-dimensional [6], and som e of the alkali fulleride salt [7] metals. It is based on the fact that the spin part of the conduction electron wave functions is not a pure Zeem an state but is an adm ixture of the spin up and down states due to spin-orbit (SO) coupling. As a result, momentum scattering due to phonons or impurities induces electron spin-ip, which leads to spin relaxation. Typically every m illionth m omentum scattering is accompanied by the electron spinip due to the relative weakness of the SO coupling. ( being the momentum relaxation time) Thus, T<sub>1</sub> which explains the motivation behind the e orts devoted to the spintronics applications of m etals.

A consequence of the EY theory is the so-called E lliottrelation, i.e. a proportionality between  $T_1$  and  $\beta$ ]:

$$\frac{1}{T_1} = \frac{L}{E} \stackrel{2}{=} \frac{1}{2}$$
(1)

Here is a band structure dependent constant and for most elemental metals 1::10 (Ref. 5]). L is the SO splitting for spin up and down electrons in a valence (or unoccupied) band near the conduction band with an energy separation of E .E g. in sodium, the conduction band is 3s derived and the relevant SO state is the 2p with E = 30:6 eV and L = 0:16 eV giving (L = E)  $^2$  = 2:7  $1\overline{0}$  [4].

The E lliott-relation shows that the tem perature dependent resistivity and CESR line-width are proportional, the two being proportional to the inverse of and  $T_1$ , respectively. This enabled to test experimentally its validity for the above mentioned range of metals. Much as the E lliott-relation has been con rmed, it is violated in M gB<sub>2</sub> as therein the CESR line-width and the resistivity are not proportional above 150 K [B].

Here, we study this anomaly using M gB<sub>2</sub> sam ples with di erent B isotopes and in purity concentrations and we show that the anomalous e ect is indeed intrinsic to M gB<sub>2</sub>. We explain the anomaly with an exact treatment of the SO scattering of conduction electrons in the presence of a nearby band with energy separation E, by extending the M ori-K awasaki form ula developed for localized spins to itinerant electrons. The result shows that the Elliott-relation breaks down when E is com – parable to ~= . A drian deduced a similar result with a qualitative argument [9].

The role of E is disregarded in the EY theory since typical values are E 10 eV and  $\sim = 2 k_B T 6 \text{ m eV}$  at T = 100 K and = 0.1 electron-phonon coupling. We show that the occurrence of the anomaly in M gB<sub>2</sub> is related to the unique features in its band structure and the large electron-phonon coupling.

W e perform ed CESR m easurem ents on three kinds of ne powder M gB<sub>2</sub> with isotope pure <sup>10</sup>B, <sup>11</sup>B, and naturalboron (20 % <sup>10</sup>B and 80 % <sup>11</sup>B). The sam ples have



FIG. 1: Comparison of the temperature dependent CESR line-width ( :  $M g^{11}B_2$ ,  $M gB_2$  of natural boron) and the resistance (solid curve) for  $M g^{11}B_2$ . The two types of data overlap in the 40-150 K temperature range. A representative error bar is show n.

slightly di erent in purity content, shown by the varying residual CESR line-width, B<sub>0</sub>. The temperature dependent  $T_1$  and the CESR line-width, B, are related:  $B = B_0 + 1 = T_1$ , where = 2 = 28 G H z/T is the electron gyrom agnetic factor. ESR spectroscopy was done on a Bruker X -band spectrom eter (center eld 0.33 T) in the 4-700 K tem perature range on sam ples sealed under He in quartz tubes. The most important result of the current report, the anom alous tem perature dependence of B or  $T_{1}$ , is independent of sample morphology, isotope content, or therm al history. B is also independent of the magnetic eld, apart from a small change in B  $_{0}$ [10]. Resistance on pellet samples and SQUID magnetom etry were studied on the same batch as those used for ESR.TheRRR > 20 and the sharp (< 0.5 K) superconducting transition attest the high quality of the sam ples. Heating the samples in the ESR measurement (about 1 h duration) to 700 K does not a ect the superconducting properties as shown by magnetization measurements.

W e reported previously the anom abustem perature dependence of the CESR line-width in M g<sup>11</sup>B<sub>2</sub>: although the line-width follows the resistance for the 40-150 K tem perature range, it deviates above 150 K and saturates above 400 K [8]. This was con med independently [11, 12]. To our know ledge, this is the only known metal where such phenom enon is observed. We extended the previousm easurement to 700 K and the result is shown in Fig. 1. Interestingly, the CESR line-width does not just saturate at high tem peratures, as found previously, but decreases slightly above 500 K. The result is reversible upon cooling with no dependence on the therm al treatment protocol. The phenom enon is reproduced on several sam ples of di erent purity and boron isotopes, thus it is intrinsic to M  ${\rm gB}_2$  .

W e explain the anom alous tem perature dependence of  $T_1$  in generalbefore including the speci cs of M gB<sub>2</sub>. The E lliott-Y afet theory disregards the magnitude of and takes life-time e ects only to lowest order into account [3, 4]. The extended description involves the K ubo-form alism and is based on a two-band m odel H am iltonian,  $H = H_0 + H_{SO}$ , where:

Here ;  $^{0} = 1 \text{ or } 2$  are the band, s;s<sup>0</sup> are spin indices, L<sub>s;s<sup>0</sup></sub> is the SO coupling, and B is the magnetic eld along the z direction. H<sub>scatt</sub> is responsible for the nite . The SO coupling does not split spin up and down states in the same band for a crystal with inversion symmetry, how ever it joins di erent spin states in the two bands [1]. The Ham iltonian in Eq. 2 is essentially the same as that considered by E lliott [3]. How ever, instead of a tim e-dependent perturbation treatment, we calculate T<sub>1</sub> from the M ori-K aw asaki form ula [13, 14]:

$$\frac{1}{T_1} = \frac{1}{2_{0B}} \operatorname{Im} G_{PP^+}^{R} (!_L); \qquad (3)$$

where  $_0$  is the static magnetic susceptibility,  $!_L = B$  is the Larm or frequency, and  $G_{PP^+}^R$  (!) is the Fourier transform of

$$G_{PP^{+}}^{R}(t) = i (t)hP(t);P^{+}(0)]i_{H_{0}};$$

$$P = [H_{SO};S^{+}]:$$
(4)

The expectation value in Eq. 4. is evaluated with the unperturbed H am iltonian, H  $_{0}$ .

Assuming that the two bands are separated by  $E(k) = {}_{1}(k) {}_{2}(k) = \sim !(k)$ , a standard calculation yields [15]:

$$\frac{1}{T_{1}} = -\frac{L_{z}^{2}(k_{F}) + 2j_{\#;"}(k_{F})f}{\sim^{2}} \frac{1}{1 + (!(k_{F}))f} ; (5)$$

where the h:::im eans Ferm isurface averaging,  $L_z(k) = L_{";"}(k)$   $L_{\#;\#}(k)$ , and we neglected  $!_L$ , which is small compared to  $!(k_F)$ . Eq. 5. was previously deduced by A drian using a qualitative argument, which involved an elective magnetic eld, L=~, uctuating with correlation time due to the SO coupling [9].

W e approximate Eq. 5 using e ective values for the band-band energy separation and the SO coupling:



FIG. 2: (Color online) Schematics of the spin-lattice relaxation in MgB<sub>2</sub> in the two-band model framework. The arrow thicknesses represent the relaxation rates (not to scale). Note that the inter-band momentum scattering rate is larger than the spin-lattice relaxation rates, therefore there is a spin transfer between the two types of bands.

$$\frac{1}{T_1} = \frac{L_e^2}{\sim^2} \frac{1}{1 + \frac{2}{e}} \frac{2}{2};$$
 (6)

This result returns the E lliott-relation when  $!_e$  1 and gives a decreasing spin relaxation rate with increasing <sup>1</sup> when  $!_e$  1, thus it can be regarded as a generalization of the E lliott-Y afet theory. In the following, we show that it describes the spin relaxation in M gB<sub>2</sub>.

Electronic properties of  $M gB_2$  are described by the so-called two-band model meaning that the conduction bands related to the boron and bonds have di erent electron-phonon couplings, di erent a nity to defects, and that the inter-band momentum scattering is weaker than the intra-band ones [16]. As a result, the conductivity is given by a parallel resistor form ula [16], i.e. the band with longer dom inates the transport. In contrast, the CESR spin relaxation is dom inated by the band with shorter T1. A lthough the inter-band m om entum scatteris longer than the intra-band momentum ing time, scattering tim es, and , it is still much shorter than T<sub>1</sub>. Thus an electron with a given spin state is scattered back and forth between the two types of bands several times before ipping its spin, which is depicted in Fig. 2. The overall  $1=T_1$  is the average of the spin-lattice relaxation rates weighted by the relative DOS on the and bands, N = 0.56 and N = 0.44 [17]:

$$\frac{1}{T_1} = \frac{N}{T_{1;}} + \frac{N}{T_{1;}}$$
(7)

In Fig. 3., we show the band structure of M  $gB_2$  from Refs. [18, 19] near the Fermi energy. Two boron and



FIG. 3: (Color online). Band structure of M gB<sub>2</sub> near the Ferm ienergy after R efs. [18, 19]. Two of the bands (black) cross the Ferm i surface near each other in the vicinity of the and A points, whereas bands (red) are separated from other bands with a larger optical gap at the crossing. We also show the dispersion with 8 times larger wave-vector resolution around the points with vertical arrows for possible E values.

two bands cross the Ferm ienergy such that the bands are well separated from other bands with E 2 eVwhereas the two bands are close to each other and E 0.2 eV. Based on the above theory and Eq. 6., we conclude that  $T_1$  follows the EY mechanism for the

bands, whereas it is described the by the novel m ech-anism for the bands. W ith this in m ind and the two band m odel result of Eq. 7, we describe the CESR line-width with:

$$B = B_{0} + \frac{1}{2} - \frac{N_{e}L_{e}^{2}}{\frac{1}{2}} + \frac{N_{e}L_{e}^{2}}{1 + \frac{1}{2}} + \frac{N_{e}L_{e}^{2}}{1 + \frac{1}{2}}$$
(8)

where we introduced the band index for the parameters. Them om entum relaxation times are calculated using the Debye-m odeland assuming clean samples, i.e. zero residual scattering:

$$\frac{1}{n} = \frac{2 \ k_{\rm B} \, \mathrm{T} \ {}_{\rm tr;n}}{\sim} \frac{Z \ {}_{\rm P}}{0} \frac{\mathrm{d}}{!_{\rm D}} - \frac{4}{!_{\rm D}} \frac{\#_2}{\sinh \frac{\omega}{2k_{\rm B} \, \mathrm{T}}}; (9)$$

where n = ;,  $!_D$  is the D ebye frequency, and tr;n are the transport electron-phonon couplings from R ef. [16], which contain both intra- and inter-band scattering.



FIG. 4: Measured (symbols) and calculated (solid curves) CESR line-width in MgB<sub>2</sub> with <sup>11</sup>B and <sup>10</sup>B.N ote the larger residual line-width in the latter sample. D ashed curves show the contributions to the line-width from the and bands for the <sup>11</sup>B.D otted curve shows a calculation for the the <sup>11</sup>B sample assuming 1=T<sub>1</sub> is due to bands only.

In Fig. 4., we show the CESR line-width for  $M g^{11}B_2$ and M g<sup>10</sup>B<sub>2</sub> between 40 and 700 K and the calculated line-width using Eq. 8. with parameters in Table I. obtained from a t. Results on the natural boron sample are identical to the data on the  $M g^{11}B_2$  within experin ental error and are not shown. The larger residual line-width in the  ${}^{10}B$  (B  $_0 = 2 \text{ mT}$ ) than in the  ${}^{11}B$ sample (B  $_0 = 1 \text{ mT}$ ) is related to a larger defect concentration in the starting boron, the preparation m ethod and the starting Mg being identical. Apart from this, the only di erence between the two sam ples are the different Debye tem perature, D. The calculated CESR line-width (solid curves) reproduces well the experim ental data with the parameters in Table I. The dotted curve in Fig. 4. is a calculation assuming that relaxation is given by the bands alone, which accounts relatively well for the data with three free parameters (L , E  $_{\rm e}$  ; , and B  $_0$ ). However, it fails to reproduce the slope of B at higher tem peratures, which shows the need to include relaxation due to the bands.

The determ ination of E  $_{\rm e}$ ; 0.2 eV is robust as it is given by the temperature where the maximal B is attained and its value is close to values expected from the band structure (arrows in Fig. 3.). Know ledge of E  $_{\rm e}$ ; allows to determ ine the SO splitting independently,  $L_{\rm e}$ ; = 0.64 m eV, as usually only the L= E ratio is known. The SO splitting for the atom ic boron 2p orbital is L = 0.23 m eV (Ref. [4]), which is in a rea-

TABLE I: Param eters used to calculate the CESR line-width in MgB\_2. The given standard deviations indicate the free param eters of the t.

								-
tr	[16]	L <sub>e</sub> (	L <sub>e</sub> (meV)		V)	D	(K)	
						<sup>11</sup> B	<sup>10</sup> B	
1.09	0.46	0.64 (2)	2.8(1)	0.194 (5)	2	535 (15)	555 (15)	
								-

sonable agreem ent with the experim ental value. E was xed to 2 eV which a ects L  $_{\rm e}$  ; as these are not independent.

The isotope e ect on  $p^{D}$  is  $p^{10}$   $p^{-11}$   $p^{$ 

Finally, we note that the maximum of  $1=T_1$  occurs when ! 1. This coincides with the Io e-Regeleriterion for the electron transport [23] when the band-band separation is comparable to the bandwidth, w, e.g. in narrow band m etals. For M gB<sub>2</sub>, w 10 eV [8] therefore saturation of the CESR line-width is not accompanied by a saturation of electrical resistivity.

In conclusion, we explained the anom abus spin-lattice relaxation in M gB<sub>2</sub> by extending the E lliott-Y affet theory to the case of rapid m on entum scattering and near lying bands. The anom aly does not occur in conventionalm etals, which have sm all electron-phonon coupling and well separated bands. A similar phenom enon, the so-called D yakonov-P erel relaxation [1], occurs for sem iconductors without inversion symm etry, although its physical origin is di erent. The band structure of some of the other diborides in e.g. BeB<sub>2</sub> and CaB<sub>2</sub> predicts [19] similar phenom ena but conventional spin relaxation in A B<sub>2</sub>, ScB<sub>2</sub>, and YB<sub>2</sub>. We also predict that the described e ect is sensitive to pressure since this shifts the bands [24].

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Corresponding author: sim on@esrphybme.hu

<sup>y</sup> P resent address: IFW D resden, Institute for Solid State R esearch, P.O.B ox 270116, D-01171 D resden, G erm any

<sup>z</sup> P resent address: C ondensed M atter P hysics and M aterials Science D epartm ent, B rookhaven N ational Laboratory, U pton, N ew York 11973-5000, U SA E lectronic address: sim on@ esrphy bm e hu

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